



R U N A U

Jiangsu Runau Electronics Manufacturing Co.,Ltd

ZP7500-Rectifier Diode

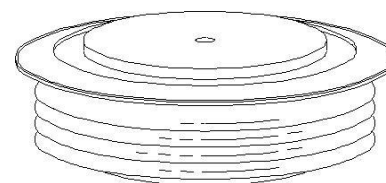
1800 - 2400 V_{RRM}

GENERAL PURPOSE HIGH POWER STANDARD RECTIFIER

Features:

- . All Diffused Structure
- . High Surge rating
- . Blocking capability up to 2400 volts
- . Ceramic Housing Hermetic Package
- . Pressure Assembled Device

ZT110cT



ELECTRICAL CHARACTERISTICS AND RATINGS

Reverse Blocking

Device Type	V _{RRM} (1)	V _{RSM} (1)
ZP7500-18	1800	2000
ZP7500-20	2000	2200
ZP7500-22	2200	2400
ZP7500-24	2400	2600

Notes:

All ratings are specified for T_j=25 °C unless otherwise stated.

(1) All voltage ratings are specified for an applied 50Hz/60Hz sinusoidal waveform over the temperature range 0 to +175 °C.

(2) 10 msec. max. pulse width

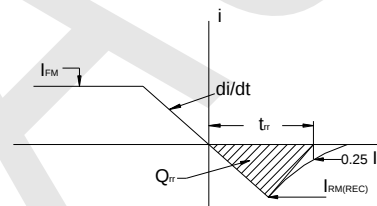
(3) Maximum value for T_j = 175 °C.

(4) See parameter definition below:

V_{RRM} = Repetitive peak reverse voltage

V_{RSM} = Non repetitive peak reverse voltage (2)

Repetitive peak reverse leakage	I _{RRM}	5 mA 200 mA (3)
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REVERSE RECOVERY CHARACTERIST

Conducting - on state

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Average forward current	I _{F(AV)}		7500		A	Sinewave, 180°, T _c =100°C
RMS forward current	I _{FRMS}		11775		A	Nominal value
Peak one cycle surge (non repetitive) current	I _{FSM}		90000		A	10 msec (50Hz), sinusoidal wave-shape, 180° conduction, T _j = 175 °C
I square t	I ² t		4×10 ⁷		A ² s	10 msec
Peak forward voltage	V _{FM}		1.15		V	I _{FM} = 5000A;T _j =25°C
Threshold voltage	V _{FO}		0.82		V	T _j =175°C,I=0.5π I _{F(AV)} to 1.5π I _{F(AV)}
Slope resistance	r _F		0.04		mΩ	T _j =175°C,I=0.5π I _{F(AV)} to 1.5π I _{F(AV)}
Reverse Recovery Current (4)	I _{RM(REC)}				A	I _{FM} = 500 A; di/dt = -10 A/s;T _j _{max}
Reverse Recovery Charge (4)	Q _{rr}			6000	μC	I _{FM} = 500 A; di/dt = -10 A/s;T _j _{max}
Reverse Recovery Time (4)	t _{rr}				μs	I _{FM} = 500 A; di/dt = -10 A/s;T _j _{max}

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Operating temperature	T_j	-40	+175		$^{\circ}\text{C}$	
Storage temperature	T_{stg}	-40	+175		$^{\circ}\text{C}$	
Thermal resistance - junction to case	$R_{\Theta(j-c)}$		0.006		$^{\circ}\text{C/W}$	Double sided cooled
Thermal resistance - case to heatsink	$R_{\Theta(c-s)}$		0.0015		$^{\circ}\text{C/W}$	Double sided cooled
Mounting force	P	65	85	80	kN	
Weight	W			1.9	kg.	

* Mounting surfaces smooth, flat and greaseless

CASE OUTLINE AND DIMENSIONS

